



浙江世菱半导体有限公司  
ZHEJIANG SHILING SEMICONDUCTOR CO.,LTD.

## 产品规格书

Specification of products

产品名称：可控硅模块

产品型号：MTC162A

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ZHEJIANG SHILING SEMICONDUCTOR CO., LTD.

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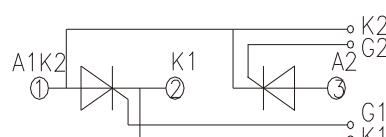
[Http://www.smrshiling.com](http://www.smrshiling.com)

拟制	审核	核准
林益龙	曹剑龙	宗瑞

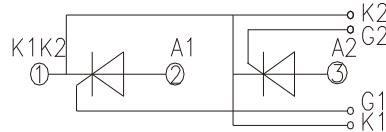
SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T <sub>J</sub> (°C)	VALUE			UNIT
				Min	Type	Max	
I <sub>T(AV)</sub> I <sub>F(AV)</sub>	Mean on-state current	180° half sine wave 50Hz Single side cooled, T <sub>C</sub> =85°C	125			162	A
I <sub>T(RMS)</sub>	RMS on-state current	Single side cooled, T <sub>C</sub> =85°C	125			255	A
V <sub>DRM</sub> V <sub>RRM</sub>	Repetitive peak off-state voltage Repetitive peak reverse voltage	V <sub>DRM</sub> &V <sub>RRM</sub> tp=10ms V <sub>DsM</sub> &V <sub>RsM</sub> = V <sub>DRM</sub> &V <sub>RRM</sub> +200V respectively	125		1200		V
I <sub>DRM</sub> I <sub>RRM</sub>	Repetitive peak current	at V <sub>DRM</sub> at V <sub>RRM</sub>	125			20	mA
I <sub>TSM</sub>	Surge on-state current	10ms half sine wave	125			5.20	KA
I <sup>2</sup> t	I <sup>2</sup> T for fusing coordination	V <sub>R</sub> =60%V <sub>RRM</sub>				139 A <sup>2</sup> s*10 <sup>3</sup>	
V <sub>TO</sub>	Threshold voltage		125			1.7	V
r <sub>T</sub>	On-state slop resistance					1.69 mΩ	
V <sub>TM</sub>	Peak on-state voltage	I <sub>TM</sub> =486A	125			1.40	V
dv/dt	Critical rate of rise of off-state voltage	V <sub>DM</sub> =67%V <sub>DRM</sub>	125			800 V/μ	
di/dt	Critical rate of rise of on-state current	From 67%V <sub>DRM</sub> to 405A, Gate source 1.5A t <sub>r</sub> ≤0.5 μs Repetitive	125			100 A/μ	
I <sub>GT</sub>	Gate trigger current		25	20		150 mA	
V <sub>GT</sub>	Gate trigger voltage	V <sub>A</sub> =12V, I <sub>A</sub> =1A		0.8		2.0 V	
I <sub>H</sub>	Holding current			20		100 mA	
V <sub>GD</sub>	Non-trigger gate voltage	At 67%V <sub>DRM</sub>	125			0.2 V	
R <sub>th(j-c)</sub>	Thermal resistance Junction to heatsink	At 180° sine Single side cooled				0.200 °C/W	
V <sub>iso</sub>	Isolation voltage	50Hz, RMS, t=1min, I <sub>iso</sub> : 1mA (MAX)		2500			V
F <sub>m</sub>	Thermal connection torque(M6)				5.0		N.m
	Mounting torque(M6)				5.0		N.m
T <sub>stg</sub>	Stored temperature			-40		140 °C	
W <sub>t</sub>	Weight				305		g
Outline							

## OUTLINE DRAWING & CIRCUIT DIAGRAM

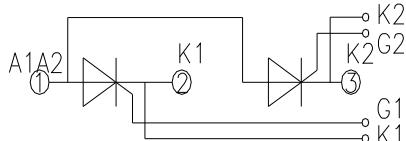
MTC



MTK



MTA



## Rating and Characteristic

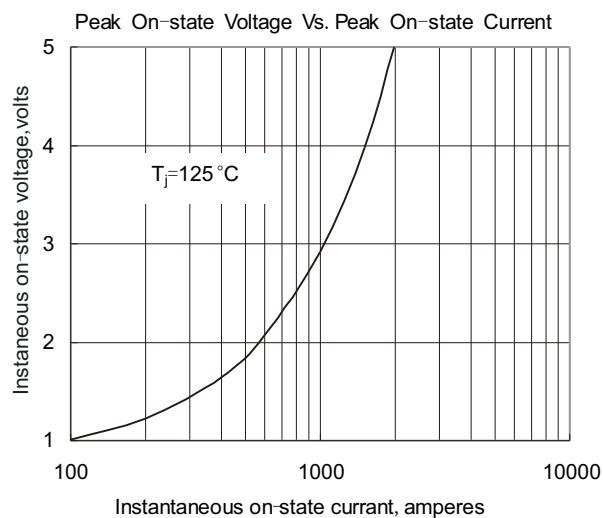


Fig.1

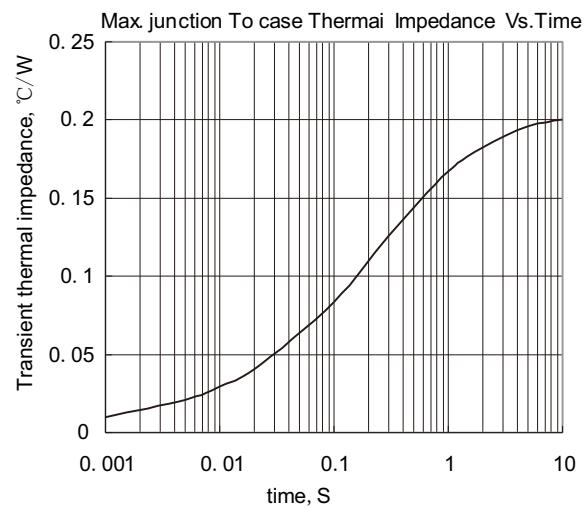


Fig.2

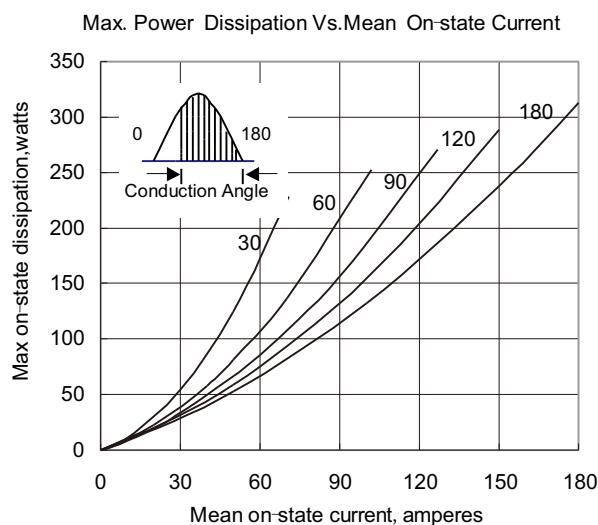


Fig.3

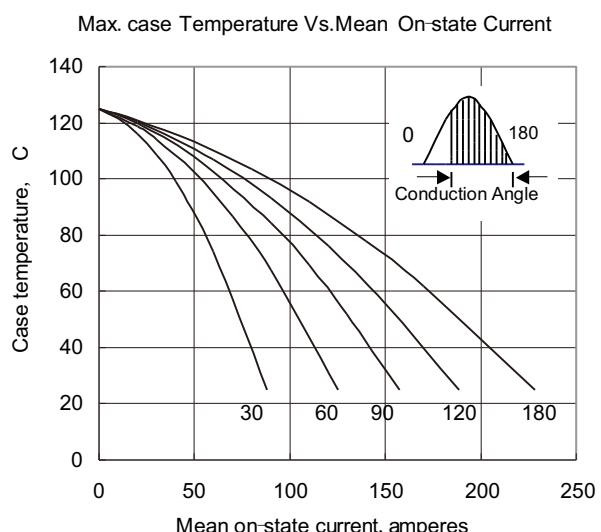


Fig.4

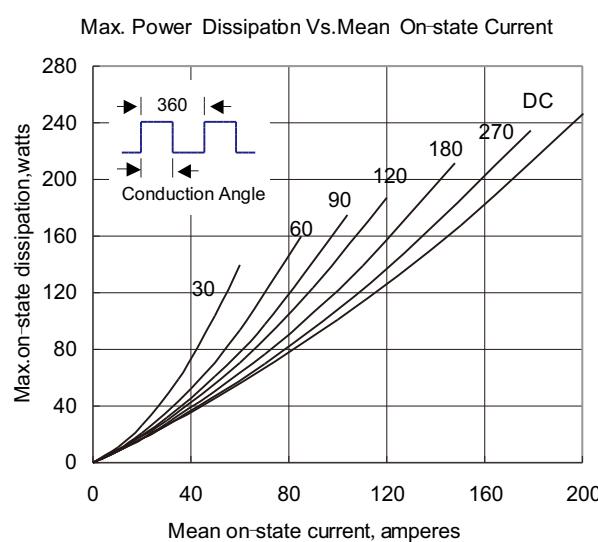


Fig.5

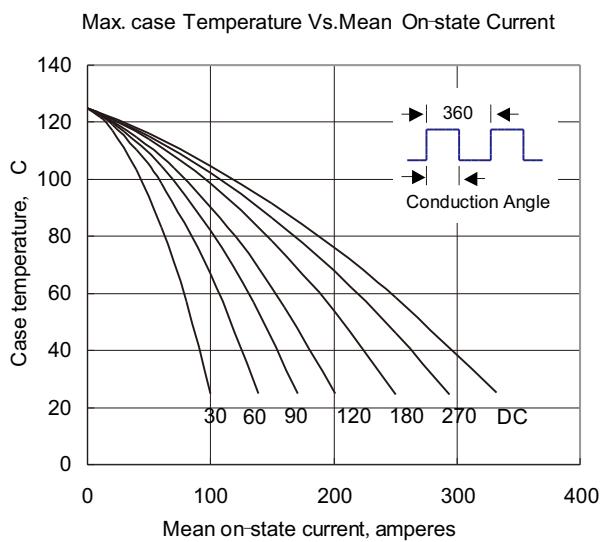


Fig.6

## Rating and Characteristic

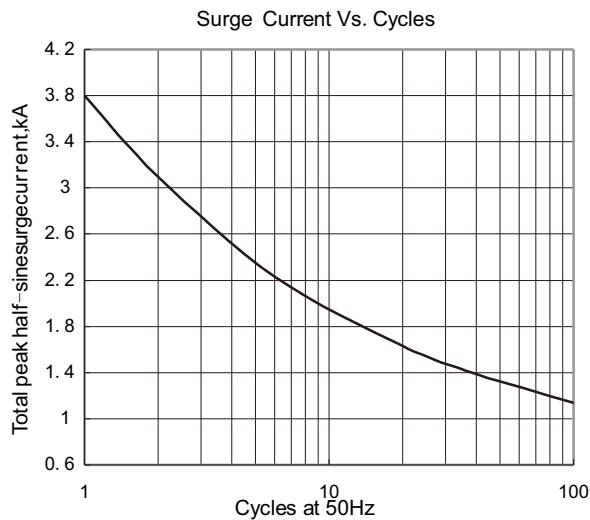


Fig. 7

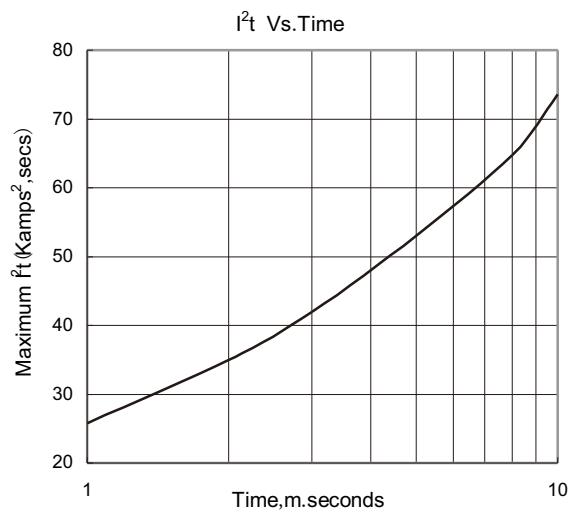


Fig. 8

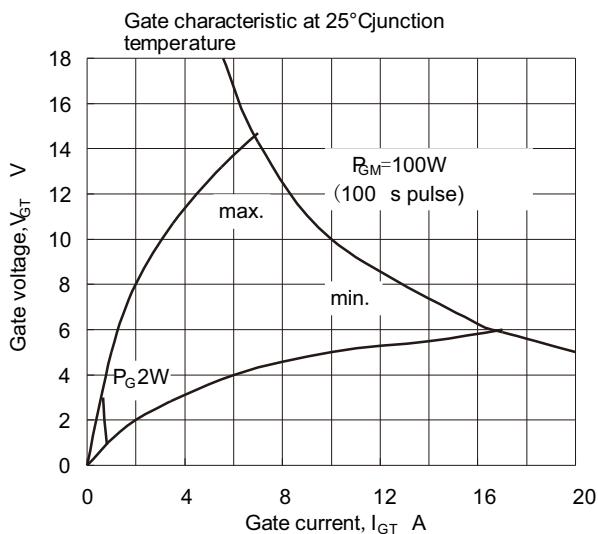


Fig. 9

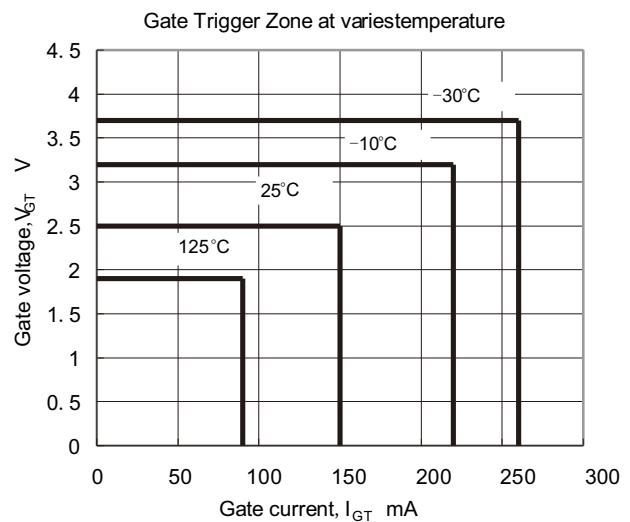


Fig. 10

## Outside Dimension

